

HD74BC245A

Octal Bus Transceivers With 3 State Outputs

HITACHI

ADE-205-008A (Z)

Rev. 1

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Description

The HD74BC245A provides high drivability and operation equal to or better than high speed bipolar standard logic IC by using Bi-CMOS process. The device features low power dissipation that is about 1/5 of high speed bipolar logic IC, when the frequency is 10 MHz. The device has ten buffers with three state outputs in a 20 pin package. Each device has an active low enable input \bar{G} and a direction control input DiR. When DiR is high, data flows from the A inputs to the B outputs. When DiR is low, data flows from the B inputs to the A outputs. When G is high, disables both A and B ports by placing them in a high impedance.

Features

- Input/Output are at high impedance state when power supply is off.
- Built in input pull up circuit can make input pins be open, when not used.
- TTL level input
- Wide operating temperature range
 $T_a = -40$ to $+85^\circ\text{C}$

Function Table

Control Inputs

\bar{G}	DiR	Operation
L	L	B data to A bus
L	H	A data to B bus
H	X	Z

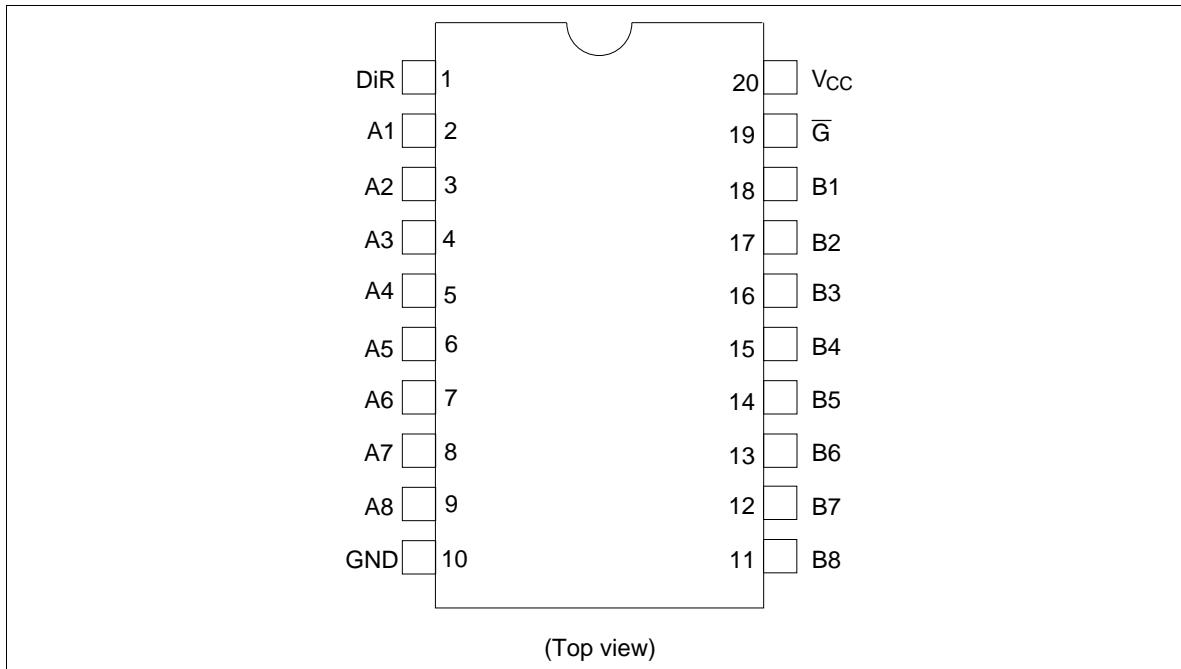
H : High level

L : Low level

Z : High impedance

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Pin Arrangement



Absolute Maximum Ratings

Item	Symbol	Rating	Unit
Supply voltage	V_{CC}	−0.5 to +7.0	V
Input diode current	I_{IK}	±30	mA
Input voltage	V_{IN}	−0.5 to +7.5	V
Output voltage	V_{OUT}	−0.5 to +7.5	V
Off state output voltage	$V_{OUT(off)}$	−0.5 to +5.5	V
Storage temperature	T_{STG}	−65 to +150	°C

Note: 1. The absolute maximum ratings are values which must not individually be exceeded, and furthermore, no two of which may be realized at the same time.

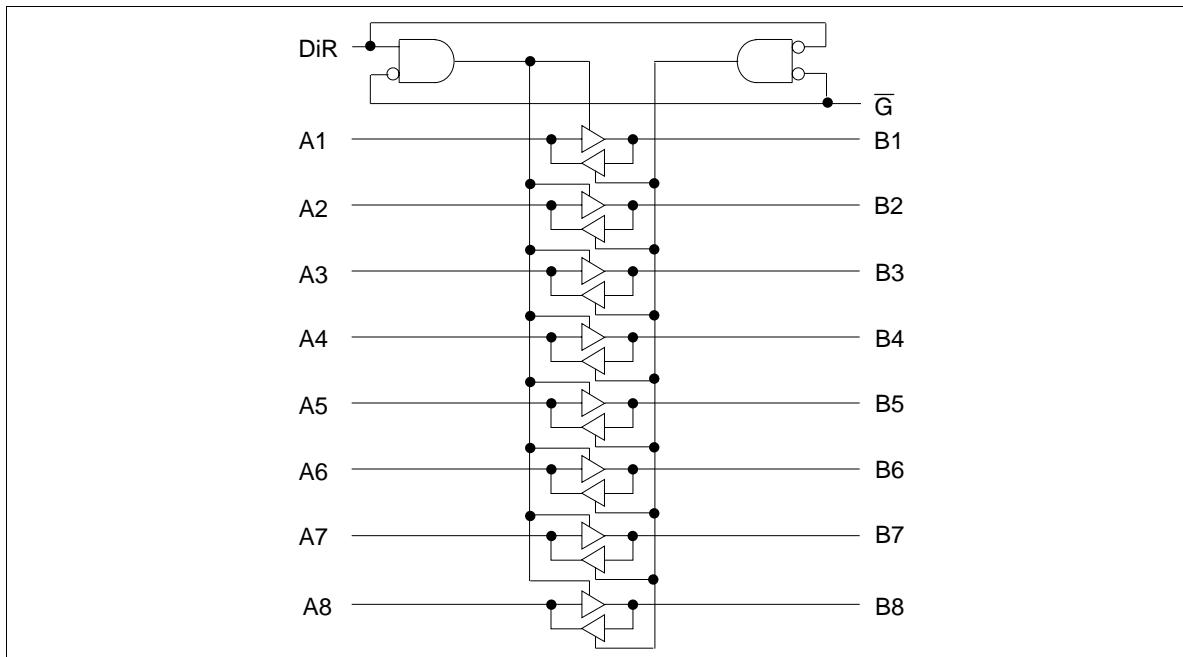
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Recommended Operating Conditions

Item	Symbol	Min	Typ	Max	Unit
Supply voltage	V_{CC}	4.5	5.0	5.5	V
Input voltage	V_{IN}	0	—	V_{CC}	V
Output voltage	V_{OUT}	0	—	V_{CC}	V
Operating temperature	$Topr$	-40	—	85	°C
Input rise/fall time ^{*1}	t_r, t_f	0	—	8	ns/V

Note: 1. This item guarantees maximum limit when one input switches.
Waveform: Refer to test circuit of switching characteristics.

Logic Diagram



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Electrical Characteristics (Ta = -40°C to +85°C)

Item	Symbol	V _{cc} (V)	Min	Max	Unit	Test Conditions
Input voltage	V _{IH}	2.0	—	—	V	
	V _{IL}	—	0.8	—	V	
Output voltage	V _{OH}	4.5	2.4	—	V	I _{OH} = -3 mA
		4.5	2.0	—	V	I _{OH} = -15 mA
	V _{OL}	4.5	—	0.5	V	I _{OL} = 48 mA
		4.5	—	0.55	V	I _{OL} = 64 mA
Input diode voltage	V _{IK}	4.5	—	-1.2	V	I _{IN} = -18 mA
Input current	I _I	5.5	—	-250	μA	V _{IN} = 0 V
		5.5	—	100	μA	A _n or B _n , V _{IN} = 5.5 V
		5.5	—	1.0	μA	DiR or \bar{G} , V _{IN} = 5.5 V
		5.5	—	100	μA	DiR or \bar{G} , V _{IN} = 7.0 V
Short circuit output current ^{*1}	I _{OS}	5.5	-100	-225	mA	V _O = 0 V, V _{IN} = 5.5 V
Off state output current	I _{OZH}	5.5	—	-100	μA	V _O = 2.7 V
	I _{OZL}	5.5	—	-250	μA	V _O = 0.5 V
Supply current	I _{CCL}	5.5	—	31.5	mA	V _{IN} = 0 or 5.5 V All outputs is "L"
	I _{CCH}	5.5	—	0.5	mA	V _{IN} = 0 or 5.5 V All outputs is "H"
	I _{CCZ}	5.5	—	4.5	mA	V _{IN} = 0 or 5.5 V All outputs is "Z"
	I _{CC^{*2}}	5.5	—	1.5	mA	V _{IN} = 3.4 or 0.5 V

Notes : 1. Not more than one output should be shorted at a time and duration of the short circuit should not exceed one second.

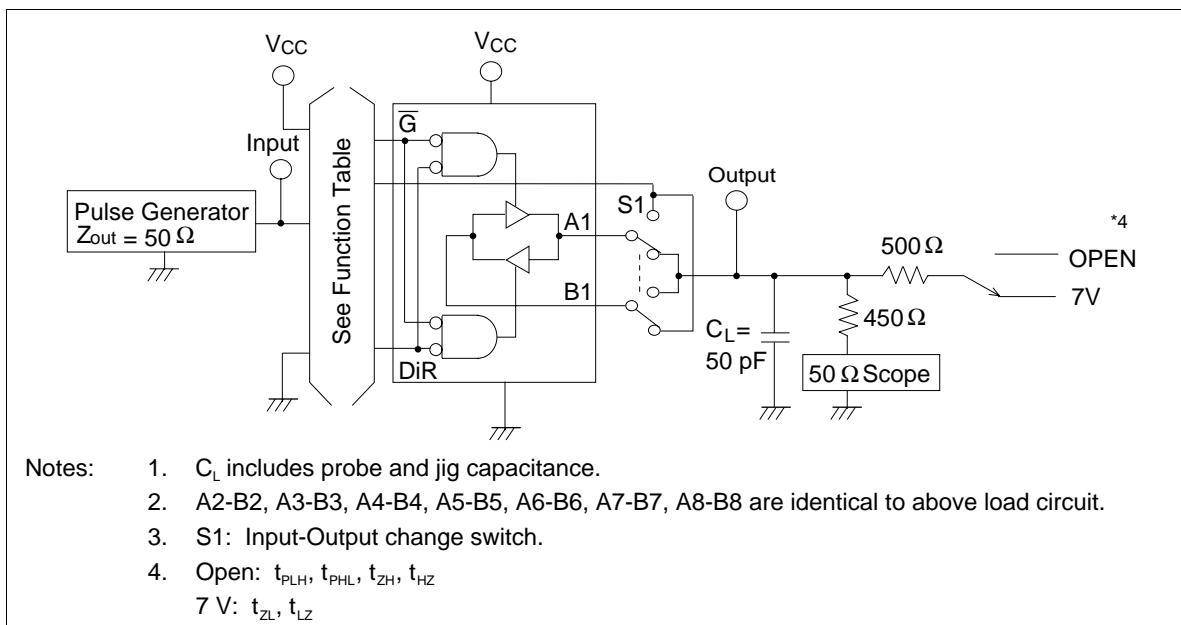
2. When input by the TTL level, it shows I_{CC} increase at per one input pin.

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Switching Test Method ($C_L = 50 \text{ pF}$)

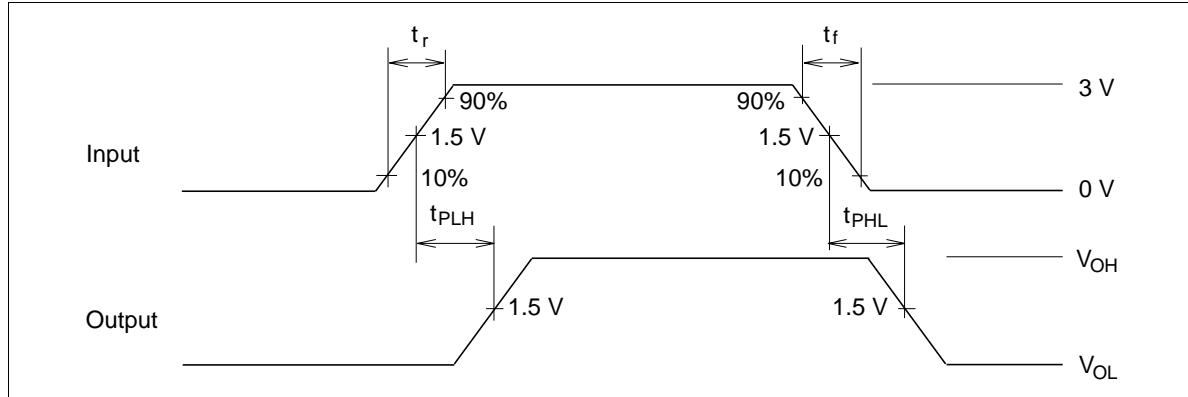
Item	Symbol	Ta = 25°C V _{cc} = 5.0 V		Ta = -40 to 85°C V _{cc} = 5.0 V ±10%		Unit	Test Conditions
		Min	Max	Min	Max		
Propagation delay time	t_{PLH}	3.0	6.0	3.0	7.0	ns	An to Bn
	t_{PHL}	3.0	6.0	3.0	7.0		
	t_{PLH}	3.0	6.0	3.0	7.0	ns	Bn to An
	t_{PHL}	3.0	6.0	3.0	7.0		
Output enable time	t_{ZH}	3.0	9.0	3.0	11.0	ns	\bar{G} to Bn
	t_{ZL}	3.0	9.0	3.0	11.0		
	t_{ZH}	3.0	9.0	3.0	11.0	ns	\bar{G} to An
	t_{ZL}	3.0	9.0	3.0	11.0		
Output disable time	t_{HZ}	3.0	8.0	3.0	10.0	ns	\bar{G} to Bn
	t_{LZ}	3.0	8.0	3.0	10.0		
	t_{HZ}	3.0	8.0	3.0	10.0	ns	\bar{G} to An
	t_{LZ}	3.0	8.0	3.0	10.0		
Input capacitance	C_{IN}	3.0(Typ)		—		pF	$V_{IN} = V_{cc}$ or GND
Output capacitance	$C_{I/O}$	15.0(Typ)		—		pF	$V_{I/O} = V_{cc}$ or GND

Test Circuit

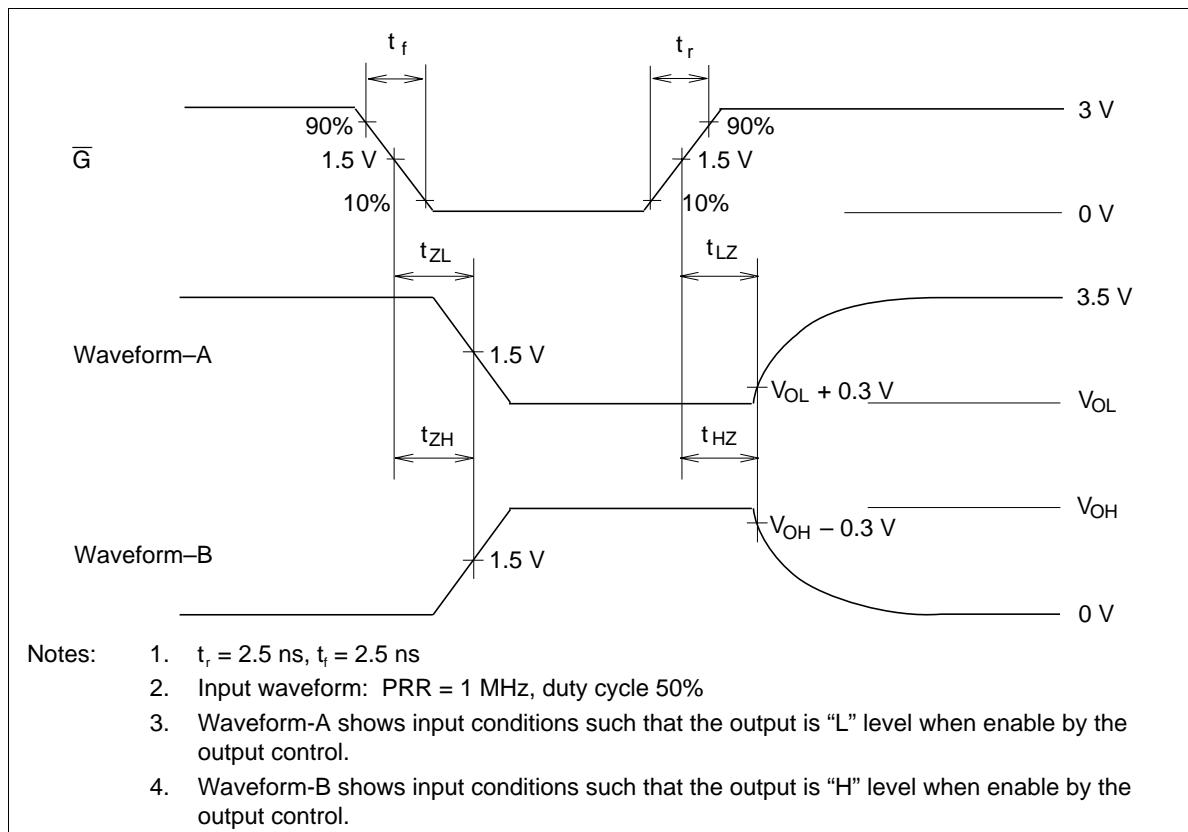


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Waveforms-1



Waveforms-2



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Package Dimensions

Unit: mm



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